

CMLM0708A

**MULTI DISCRETE MODULE™**  
**SURFACE MOUNT**  
**N-CHANNEL AND P-CHANNEL**  
**COMPLEMENTARY MOSFETS**



[www.centralsemi.com](http://www.centralsemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMLM0708A is a Multi Discrete Module™ consisting of complementary N-Channel and P-Channel Enhancement-mode MOSFETS packaged in a space saving PICOmini™ SOT-563 case. This device is designed for small signal general purpose applications where size and operational efficiency are prime requirements.

**MARKING CODE: C78**

PICOmini™

**MDM**  
Multi Discrete Module



**SOT-563 CASE**

**FEATURES:**

- Dual Complementary MOSFETS
- Low  $r_{DS(ON)}$  ( $3\Omega$  MAX @  $V_{GS}=5.0V$ )
- Small SOT-563 Surface Mount Package

**MAXIMUM RATINGS - CASE: ( $T_A=25^\circ C$ )**

Power Dissipation (Note 1)	
Power Dissipation (Note 2)	
Power Dissipation (Note 3)	
Operating and Storage Junction Temperature	
Thermal Resistance	

**MAXIMUM RATINGS: ( $T_A=25^\circ C$ )**

SYMBOL	TEST CONDITIONS	<u>N-Ch (Q1)</u>	<u>P-Ch (Q2)</u>	UNITS
$V_{DS}$	$V_{GS}=20V, V_{DS}=0$	60	50	V
$V_{DG}$	$V_{DS}=60V, V_{GS}=0$	60	50	V
$V_{GS}$	$V_{DS}=50V, V_{GS}=0$	40	20	V
$I_D$	$V_{DS}=280V, V_{GS}=0$	280	280	mA
$I_S$	$V_{DS}=280V, V_{GS}=0$	280	280	mA
$I_{DM}$	$V_{DS}=50V, V_{GS}=0$	1.5	1.5	A
$I_{SM}$	$V_{DS}=50V, V_{GS}=0$	1.5	1.5	A

**ELECTRICAL CHARACTERISTICS: ( $T_A=25^\circ C$  unless otherwise noted)**

SYMBOL	TEST CONDITIONS	<u>N-Ch (Q1)</u>		<u>P-Ch (Q2)</u>		UNITS
		MIN	MAX	MIN	MAX	
$I_{GSSF}, I_{GSSR}$	$V_{GS}=20V, V_{DS}=0$	-	100	-	100	nA
$I_{DSS}$ (N-Ch)	$V_{DS}=60V, V_{GS}=0$	-	1.0	-	-	$\mu A$
$I_{DSS}$ (P-Ch)	$V_{DS}=50V, V_{GS}=0$	-	-	-	1.0	$\mu A$
$I_{DSS}$ (N-Ch)	$V_{DS}=60V, V_{GS}=0, T_J=125^\circ C$	-	500	-	-	$\mu A$
$I_{DSS}$ (P-Ch)	$V_{DS}=50V, V_{GS}=0, T_J=125^\circ C$	-	-	-	500	$\mu A$
$I_{D(ON)}$ (N-Ch)	$V_{GS}=10V, V_{DS}=10V$	500	-	-	-	mA
$I_{D(ON)}$ (P-Ch)	$V_{GS}=10V, V_{DS}=10V$	-	-	500	-	mA
$BV_{DSS}$	$V_{GS}=0, I_D=10\mu A$	60	-	50	-	V

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of  $4.0mm^2$

(2) FR-4 Epoxy PC Board with copper mounting pad area of  $4.0mm^2$

(3) FR-4 Epoxy PC Board with copper mounting pad area of  $1.4mm^2$

R1 (18-January 2010)

CMLM0708A

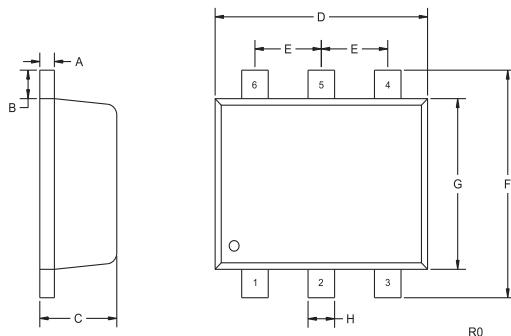
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ELECTRICAL CHARACTERISTICS - Continued:

SYMBOL	TEST CONDITIONS	N-Ch (Q1)	P-Ch (Q2)	UNITS
		MIN	MAX	
$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	1.0	2.5	V
$V_{DS(ON)}$	$V_{GS}=10V$ , $I_D=500mA$	-	1.0	V
$V_{DS(ON)}$	$V_{GS}=5.0V$ , $I_D=50mA$	-	0.15	V
$V_{SD}$ (N-Ch)	$V_{GS}=0$ , $I_S=400mA$	-	1.2	V
$V_{SD}$ (P-Ch)	$V_{GS}=0$ , $I_S=115mA$	-	-	V
$r_{DS(ON)}$	$V_{GS}=10V$ , $I_D=500mA$	-	2.0	$\Omega$
$r_{DS(ON)}$	$V_{GS}=10V$ , $I_D=500mA$ , $T_J=125^\circ C$	-	3.5	$\Omega$
$r_{DS(ON)}$	$V_{GS}=5.0V$ , $I_D=50mA$	-	3.0	$\Omega$
$r_{DS(ON)}$	$V_{GS}=5.0V$ , $I_D=50mA$ , $T_J=125^\circ C$	-	5.0	$\Omega$
$g_{FS}$ (N-Ch)	$V_{DS}=10V$ , $I_D=200mA$	80	-	$mS$
$g_{FS}$ (P-Ch)	$V_{DS}=10V$ , $I_D=200mA$	-	200	$mS$
$C_{rss}$	$V_{DS}=25V$ , $V_{GS}=0$ , $f=1.0MHz$	-	5.0	$pF$
$C_{iss}$	$V_{DS}=25V$ , $V_{GS}=0$ , $f=1.0MHz$	-	50	$pF$
$C_{oss}$	$V_{DS}=25V$ , $V_{GS}=0$ , $f=1.0MHz$	-	25	$pF$
$t_{on} / t_{off}$	$V_{DD}=30V$ , $V_{GS}=10V$ , $I_D=200mA$ $R_G=25\Omega$ , $R_L=150\Omega$	-	20	ns

SOT-563 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES	MILLIMETERS	MIN	MAX
A	0.004	0.007	0.10	0.18
B	0.008		0.20	
C	0.022	0.024	0.56	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.061	0.067	1.55	1.70
G	0.047		1.20	
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R0)

LEAD CODE:

- 1) Gate Q1
- 2) Source Q1
- 3) Drain Q2
- 4) Gate Q2
- 5) Source Q2
- 6) Drain Q1

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